

October 1987 Revised March 2002

CD4001BC/CD4011BC Quad 2-Input NOR Buffered B Series Gate • Quad 2-Input NAND Buffered B Series Gate

General Description

The CD4001BC and CD4011BC quad gates are monolithic complementary MOS (CMOS) integrated circuits constructed with N- and P-channel enhancement mode transistors. They have equal source and sink current capabilities and conform to standard B series output drive. The devices also have buffered outputs which improve transfer characteristics by providing very high gain.

All inputs are protected against static discharge with diodes to $\rm V_{DD}$ and $\rm V_{SS}.$

Features

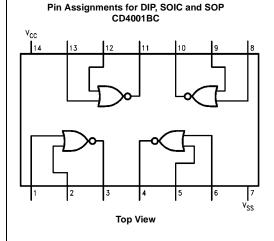
- Low power TTL: Fan out of 2 driving 74L compatibility: or 1 driving 74LS
- 5V-10V-15V parametric ratings
- Symmetrical output characteristics
- Maximum input leakage 1 µA at 15V over full temperature range

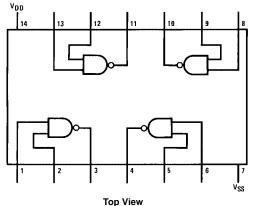
Ordering Code:

Order Number	Package Number	Package Description
CD4001BCM	M14A	14-Lead Small Outline Integrated Circuit (SOIC), JEDEC MS-012, 0.150" Narrow
CD4001BCSJ	M14D	14-Lead Small Outline Package (SOP), EIAJ TYPE II, 5.3mm Wide
CD4001BCN	N14A	14-Lead Plastic Dual-In-Line Package (PDIP), JEDEC MS-001, 0.300" Wide
CD4011BCM	M14A	14-Lead Small Outline Integrated Circuit (SOIC), JEDEC MS-012, 0.150" Narrow
CD4011BCN	N14A	14-Lead Plastic Dual-In-Line Package (PDIP), JEDEC MS-001, 0.300" Wide

Devices also available in Tape and Reel. Specify by appending the suffix letter "X" to the ordering code.

Connection Diagrams





Pin Assignments for DIP and SOIC

CD4011BC

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DS005939

CD4001BC/CD4011BC **Schematic Diagrams** CD4001BC ν_{DD} $^{1}\!/_{_{\!4}}$ of device shown $J=\overline{A\,+\,B}$ Logical "1" = HIGH Logical "0" = LOW All inputs protected by standard CMOS protection circuit. CD4011BC $^{1}\!/_{\!_{4}}$ of device shown $J=\overline{A\bullet B}$ Logical "1" = HIGH Logical "0" = LOW All inputs protected by standard CMOS protection circuit.

Absolute Maximum Ratings(Note 1)

(Note 2)

Voltage at any Pin $$-0.5\mathrm{V}$ to \ V_{DD}$ +0.5\mathrm{V}$$

Power Dissipation (P_D)

 $\begin{array}{ccc} \text{Dual-In-Line} & 700 \text{ mW} \\ \text{Small Outline} & 500 \text{ mW} \\ \text{V}_{\text{DD}} \text{ Range} & -0.5 \text{ V}_{\text{DC}} \text{ to } +18 \text{ V}_{\text{DC}} \end{array}$

Storage Temperature (T_S) Lead Temperature (T_L)

(Soldering, 10 seconds) 260°C

-65°C to +150°C

Recommended Operating Conditions

Operating Range (V_{DD}) 3 V_{DC} to 15 V_{DC}

Operating Temperature Range

CD4001BC, CD4011BC -55°C to +125°C

Note 1: "Absolute Maximum Ratings" are those values beyond which the safety of the device cannot be guaranteed. Except for "Operating Temperature Range" they are not meant to imply that the devices should be operated at these limits. The Electrical Characteristics tables provide conditions for actual device operation.

Note 2: All voltages measured with respect to $V_{\mbox{SS}}$ unless otherwise specified

DC Electrical Characteristics (Note 2)

Symbol	Parameter	Conditions	–55°C		+ 25 ° C			+125°C		Units
Syllibol	Farameter	Conditions	Min	Max	Min	Тур	Max	Min	Max	Onits
I _{DD}	Quiescent Device	$V_{DD} = 5V$, $V_{IN} = V_{DD}$ or V_{SS}		0.25		0.004	0.25		7.5	
	Current	$V_{DD} = 10V$, $V_{IN} = V_{DD}$ or V_{SS}		0.5		0.005	0.50		15	μΑ
		$V_{DD} = 15V$, $V_{IN} = V_{DD}$ or V_{SS}		1.0		0.006	1.0		30	
V _{OL}	LOW Level	$V_{DD} = 5V$		0.05		0	0.05		0.05	
	Output Voltage	$V_{DD} = 10V$ $ I_O < 1 \mu A$		0.05		0	0.05		0.05	V
		$V_{DD} = 15V$		0.05		0	0.05		0.05	
V _{OH}	HIGH Level	$V_{DD} = 5V$	4.95		4.95	5		4.95		
	Output Voltage	$V_{DD} = 10V$ $ I_O < 1 \mu A$	9.95		9.95	10		9.95		V
		$V_{DD} = 15V$	14.95		14.95	15		14.95		
V_{IL}	LOW Level	$V_{DD} = 5V, V_{O} = 4.5V$		1.5		2	1.5		1.5	
	Input Voltage	$V_{DD} = 10V, V_{O} = 9.0V$		3.0		4	3.0		3.0	V
		$V_{DD} = 15V, V_{O} = 13.5V$		4.0		6	4.0		4.0	
V_{IH}	HIGH Level	$V_{DD} = 5V, V_{O} = 0.5V$	3.5		3.5	3		3.5		
	Input Voltage	$V_{DD} = 10V, V_{O} = 1.0V$	7.0		7.0	6		7.0		V
		$V_{DD} = 15V, V_{O} = 1.5V$	11.0		11.0	9		11.0		
I _{OL}	LOW Level Output	$V_{DD} = 5V, V_{O} = 0.4V$	0.64		0.51	0.88		0.36		
	Current	$V_{DD} = 10V, V_{O} = 0.5V$	1.6		1.3	2.25		0.9		mA
	(Note 3)	$V_{DD} = 15V, V_{O} = 1.5V$	4.2		3.4	8.8		2.4		
I _{OH}	HIGH Level Output	$V_{DD} = 5V, V_{O} = 4.6V$	-0.64		-0.51	-0.88		-0.36		
	Current	$V_{DD} = 10V, V_{O} = 9.5V$	-1.6		-1.3	-2.25		-0.9		mA
	(Note 3)	$V_{DD} = 15V, V_{O} = 13.5V$	-4.2		-3.4	-8.8		-2.4		
I _{IN}	Input Current	$V_{DD} = 15V, V_{IN} = 0V$		-0.10		-10 ⁻⁵	-0.10		-1.0	μА
		$V_{DD} = 15V, V_{IN} = 15V$		0.1		10 ⁻⁵	0.10		1.0	μΛ

Note 3: I_{OL} and I_{OH} are tested one output at a time.

AC Electrical Characteristics (Note 4)

CD4001BC: $T_A = 25$ °C, Input t_f ; $t_f = 20$ ns. $C_L = 50$ pF, $R_L = 200$ k. Typical temperature coefficient is 0.3% °C.

Symbol	Parameter	Conditions	Тур	Max	Units
t _{PHL}	Propagation Delay Time,	$V_{DD} = 5V$	120	250	
	HIGH-to-LOW Level	V _{DD} = 10V	50	100	ns
		$V_{DD} = 15V$	35	70	
t _{PLH}	Propagation Delay Time,	$V_{DD} = 5V$	110	250	
	LOW-to-HIGH Level	V _{DD} = 10V	50	100	ns
		$V_{DD} = 15V$	35	70	
t _{THL} , t _{TLH}	Transition Time	$V_{DD} = 5V$	90	200	
		V _{DD} = 10V	50	100	ns
		$V_{DD} = 15V$	40	80	
C _{IN}	Average Input Capacitance	Any Input	5	7.5	pF
C _{PD}	Power Dissipation Capacity	Any Gate	14		pF

Note 4: AC Parameters are guaranteed by DC correlated testing.

AC Electrical Characteristics (Note 5)

CD4011BC: T_A = 25°C, Input t_f ; t_f = 20 ns. C_L = 50 pF, R_L = 200k. Typical Temperature Coefficient is 0.3%/°C.

Symbol	Parameter	Conditions	Тур	Max	Units
t _{PHL}	Propagation Delay,	$V_{DD} = 5V$	120	250	
	HIGH-to-LOW Level	$V_{DD} = 10V$	50	100	ns
		$V_{DD} = 15V$	35	70	
t _{PLH}	Propagation Delay,	$V_{DD} = 5V$	85	250	
	LOW-to-HIGH Level	$V_{DD} = 10V$	40	100	ns
		$V_{DD} = 15V$	30	70	
t _{THL} , t _{TLH}	Transition Time	$V_{DD} = 5V$	90	200	
		$V_{DD} = 10V$	50	100	ns
		$V_{DD} = 15V$	40	80	
C _{IN}	Average Input Capacitance	Any Input	5	7.5	pF
C _{PD}	Power Dissipation Capacity	Any Gate	14		pF

Note 5: AC Parameters are guaranteed by DC correlated testing.

Typical Performance Characteristics

Typical

Transfer Characteristics

20

VDD = 15V

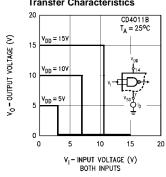
VDD = 15V

VDD = 5V

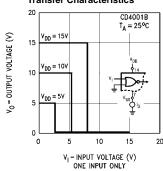
VDD = 5V

V1 - INPUT VOLTAGE (V)
ONE INPUT ONLY

Typical Transfer Characteristics

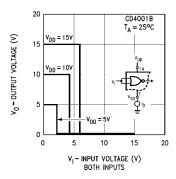


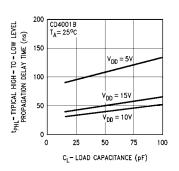
Typical Transfer Characteristics

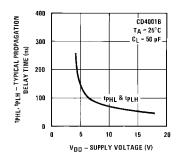


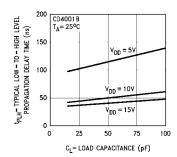
Typical Performance Characteristics (Continued)

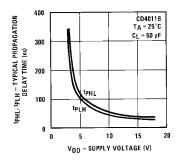
Typical Transfer Characteristics

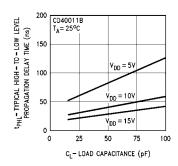




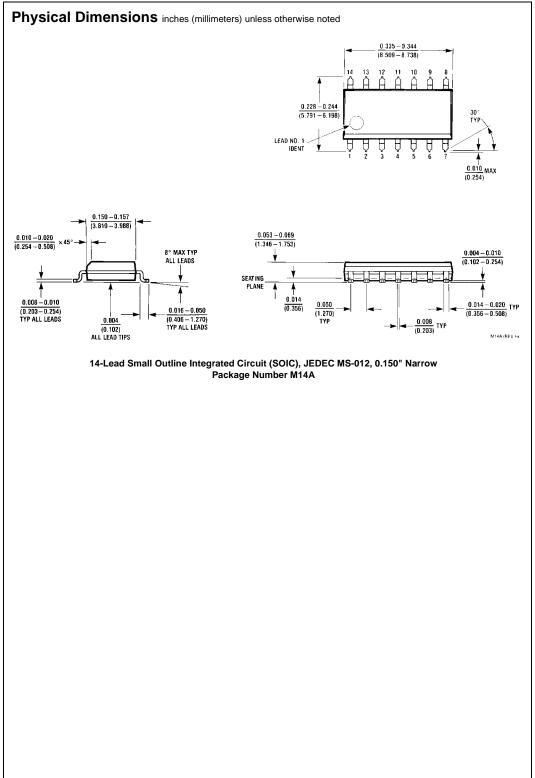


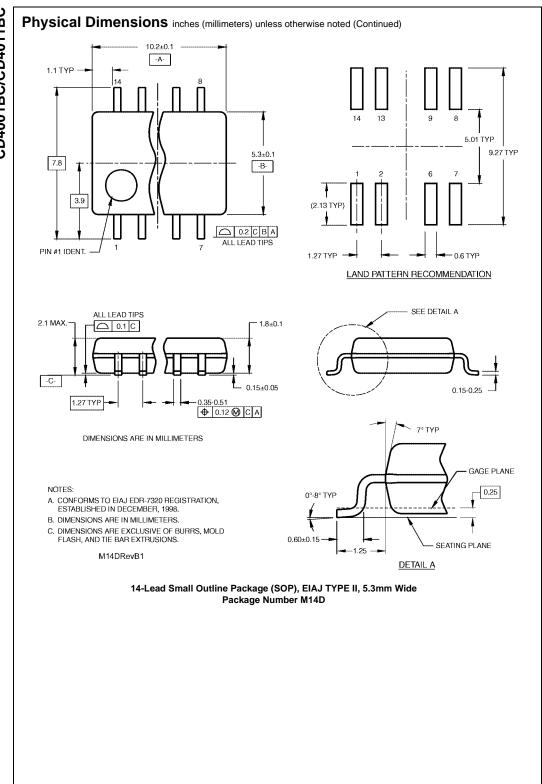




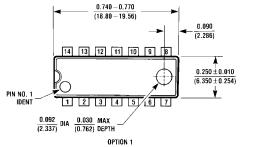


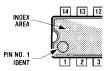
Typical Performance Characteristics (Continued) tthl, ttlh - TYPICAL TRANSITION TIME (ns) 190 CD4001B 170 CD4011B ^tPLH- TYPICAL LOW - TO - HIGH LEYEL PROPAGATION DELAY TIME (ns) 170 150 150 V_{DD} = 5V 130 110 100 90 70 50 V_{DD} = 15V 30 10 0 25 50 75 100 100 50 75 CL-LOAD CAPACITANCE (pF) CL-LOAD CAPACITANCE (pF) Atpg - PER PF OF LOAD CAPACITANCE (ns/pF) 2.0 t_r = t_f = 20 ns T_A = 25°C CD4001B CD4011B 38 IOL- TYPICAL SINK CURRENT (mA) 34 1.5 30 CD4001B CD4011B e Application Note AN - 90 Propagation Delay) 26 22 1.0 18 0.5 0 0 L 2 2 4 6 8 10 12 14 16 18 20 0 2 4 6 8 10 12 14 16 18 20 V_{DD} - POWER SUPPLY (V) v_{out} (v) IOH - TYPICAL SOURCE CURRENT (MA) 2 6 10 14 18 22 24 28 36 20 18 16 14 12 10 8 6 $v_{cc} - v_{out} (v)$



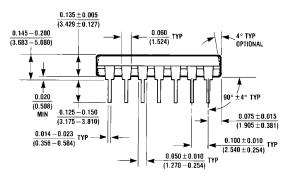


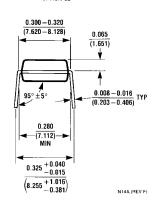
Physical Dimensions inches (millimeters) unless otherwise noted (Continued)





OPTION 02





14-Lead Plastic Dual-In-Line Package (PDIP), JEDEC MS-001, 0.300" Wide Package Number N14A

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